Measurement Sensors

Compact Laser Displacement Sensor New

HL-G1 SERIES

A variety of high-end functions are included in a compact, self-contained body for exceptional ease of use.

Easy configuration using the digital display

The built-in digital display makes it easy to configure sensor operation while checking displacement values.



DOWN key

Compact size despite the built-in controller and digital readout



Support for both NPN and PNP polarity

A single model number accommodates both NPN and PNP wiring polarity, reducing the number of model numbers that must be registered for maintenance purposes.

I/O to accommodate multiple needs

Timing input and multi input

Inaddition to timing input select the desired input according to your application: Zero set on/off Laser control Reset
Teaching

Featuring 3 outputs and an analog 2 outputs

With three outputs, the HL-G1 can be used to generate HI/GO/LOW judgment output or alarm output. The analog output can be used in both current and voltage modes.





Software tool for sensor configuration and evaluation (High functionality type only)

In addition to configuring up to 16 sensors at once, this free tool makes it easy to gather data needed for analysis, including received light waveform monitoring and data buffering. The interface language can be selected at the time of installation.

- Data buffering
- · Received light waveform display
- · Measured value display

HMI screen for HL-G1 (High functionality type only)



The GT02 / GT12 HMI operator pannel can be used in combination with the HL-G1 to allow easy confirmation of sensor status and configuration of sensor settings from a remote location. Japanese, English, Chinese (upcoming), and Korean are supported.

Select from the following HMI operator pannels: Power supply: 24 V Communications port: RS422 (RS485) • AIG02GQ 14D AIG02MQ 15D • AIG12GQ 14D/15D • AIG12MQ 14D/15D



\searrow	Туре	Standard type	High functionality	Standard type	High functionality	Standard type	High functionality	Standard type	High functionality
Item	Model No.	HL-G103-A-C5	HL-G103-S-J	HL-G105-A-C5	HL-G105-S-J	HL-G108-A-C5	HL-G108-S-J	HL-G112-A-C5	HL-G112-S-J
Measurement center distance		30 mm		50 mm		85 mm		120 mm	
Measuring range		±4 mm		\pm 10 mm		±20 mm		±60 mm	
Resolution		0.5 µm		1.5 µm		2.5 μm		8 µm	
Linearity		±0.1 % F.S.							
Temprerature characteristics		±0.08 % F.S. / °C							
Light source		Red semiconductor laser, Class 2 (IEC / JIS), Class II (FDA, Laser Notice No. 50) Max. output: 1 mW (Peak emission wavelength: 655 nm 0.026 mil)							
Beam diameter (Note 2)		0.1 $ imes$ 0.1 mm		0.5 ×1 mm		0.75 $ imes$ 1.25 mm		1.0 $ imes$ 1.5 mm	
Receiving element		CMOS image sensor							
Supply voltage		24 V DC \pm 10 % including ripple 0.5 V (P-P)							
Current consumption		100 mA or less							
Sampling rate		200 µs, 500 µs, 1 ms, 2 ms							
tnd tno Voltage	•			Output range: 0 to + 10.5 V (normal), 11 V (alarm) Output impedance: 100 Ω					
Gurrent	t	Output range: 3.2 to 20.8 mA (normal), 21.6 mA (alarm) Load impedance: 300 Ω or less							
Output (OUT 1, OUT 2, OUT 3)		Judgment output or alarm output (Setting can be selected) Selectable NPN transistor open collector or PNP transistor open collector							

Notes: 1) Where measurement conditions have not been specified precisely, the conditions used were as follows: supply voltage 24 V DC, ambient temperature +20 °C, sampling rate 200 µs, average number of samples: 1024, measurement center distance, object measured is made of white ceramic and digital measurement values.

2) This beam diameter is the size at the measurement center distance. These values were defined by using 1/e² (13.5%) of the center light intensity. If there is a slight leakage of light outside the normal spot diameter and if the periphery surrounding the sensing point has a higher reflectivity than the sensing point itself, then the results may be affected.